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Lai et al.

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(54) **PARTIAL SEMICONDUCTOR LIGHT
EMITTING COMPONENT**

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(*) Notice: This patent is subject to a terminal dis-
claimer.

(**) Term: **14 Years**

(21) Appl. No.: **29/479,543**

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(30) **Foreign Application Priority Data**

Aug. 6, 2013 (TW) 102305359

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(52) **U.S. Cl.**
USPC **D13/182**

(58) **Field of Classification Search**
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257/82, 83, 84, 103, 678, 684; 313/483,
313/494, 498, 512; 315/169.3; 345/76, 82;
428/690; 438/99, 460, 64, 65; 427/66;
361/713, 728, 679.01, 820; 324/71.5,
324/252
CPC H01L 21/00; H01L 21/02; H01L 31/00;
H01L 31/0248; H01L 31/14; H01L 31/143;
H01L 31/145; H01L 31/162; H01L 31/167;
H01L 27/14; H01L 27/288; H01L 27/30;
H01L 27/32; H01L 27/15; H01L 33/00;
H01L 33/48

See application file for complete search history.

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(57) **CLAIM**

The ornamental design for a partial semiconductor light emitting component, as shown and described.

DESCRIPTION

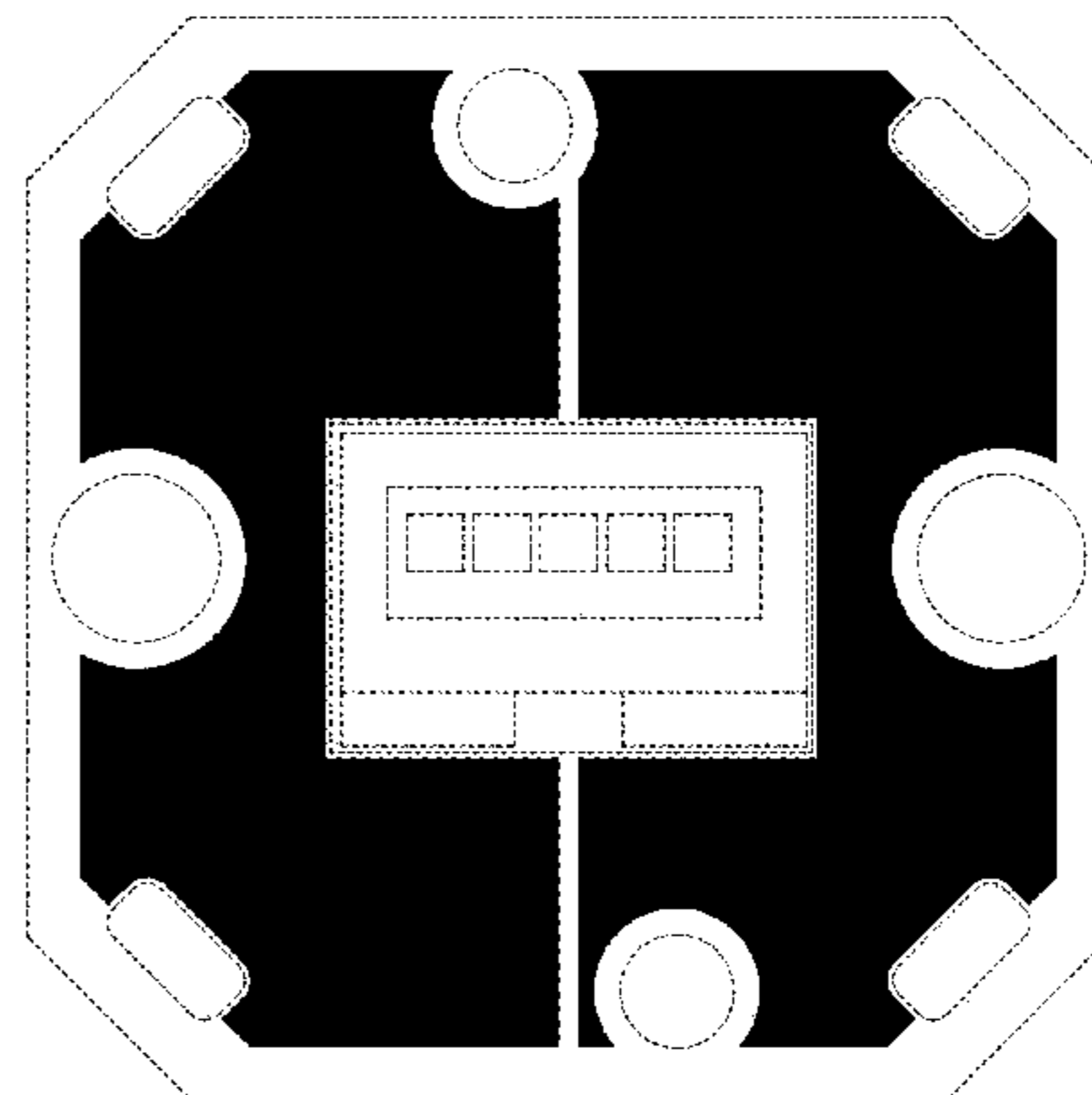
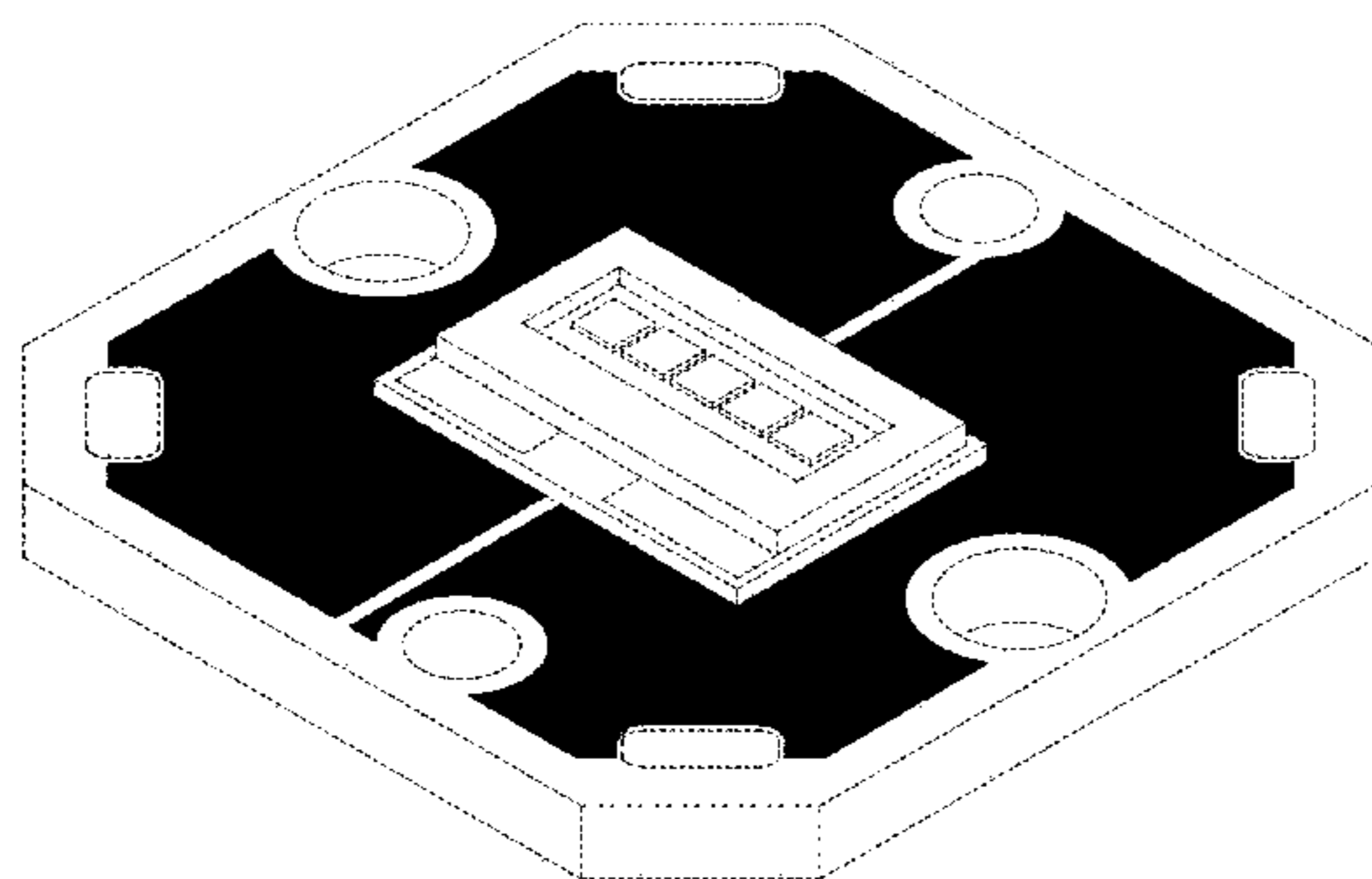
The patent or application file contains at least one drawing executed in color. Copies of this patent or patent application publication with color drawings will be provided by the Office upon request and payment of the necessary fee.

FIG. 1 is a perspective view of a partial semiconductor light emitting component showing our new design; and, FIG. 2 is a top plan view thereof.

The broken lines shown in the drawings represent unclaimed portions of the partial semiconductor light emitting component and form no part of the claimed design. A bottom plan view, a front elevation view, a rear elevation view, a right side view, and a left side view thereof form no other part of the claimed design.

The new design is the appearance of a partial semiconductor light emitting component, wherein the partial semiconductor light emitting component has a black pattern separated in two areas in a surface of the partial semiconductor light emitting component.

1 Claim, 2 Drawing Sheets
(2 of 2 Drawing Sheet(s) Filed in Color)



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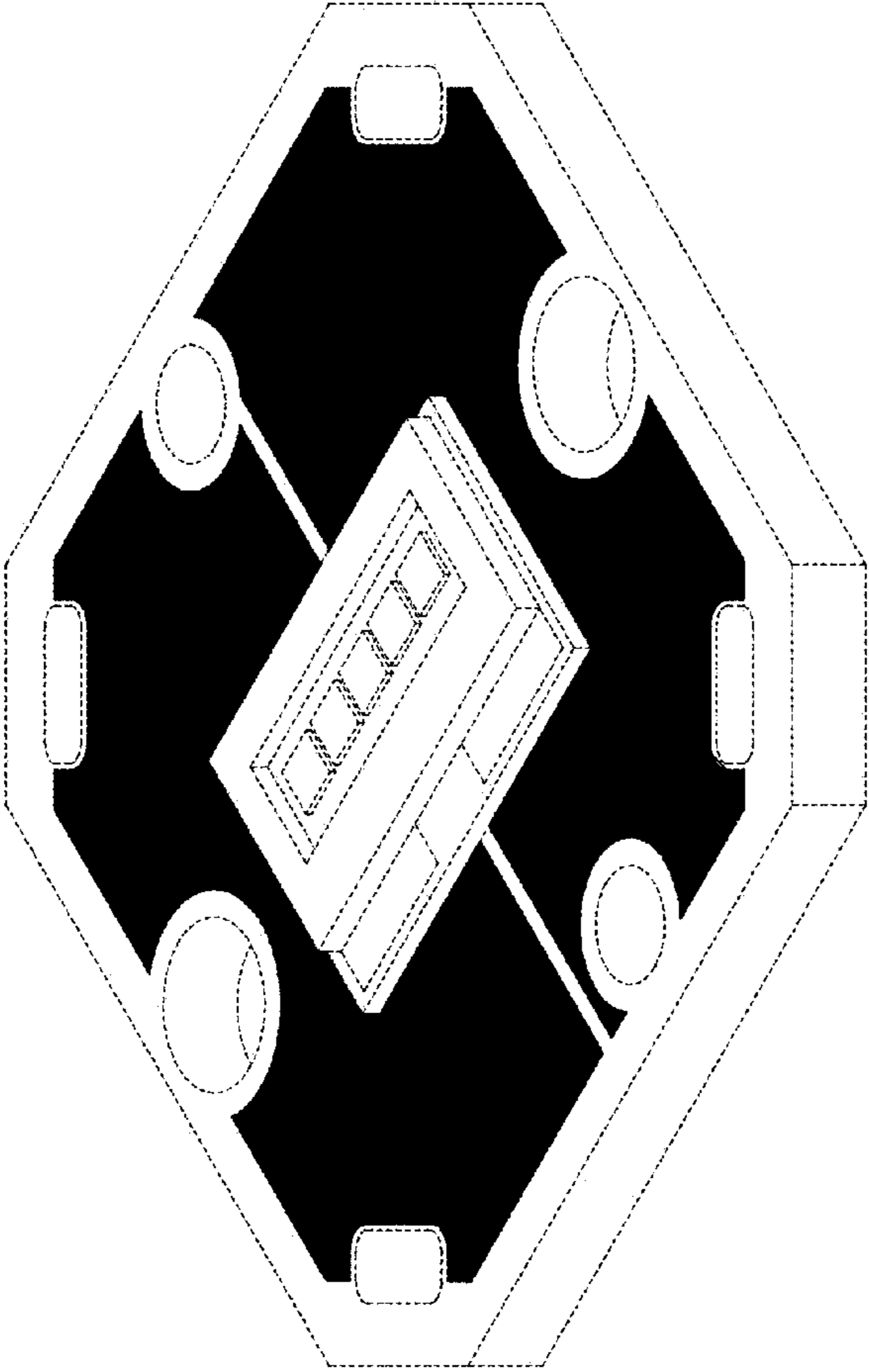


FIG. 1

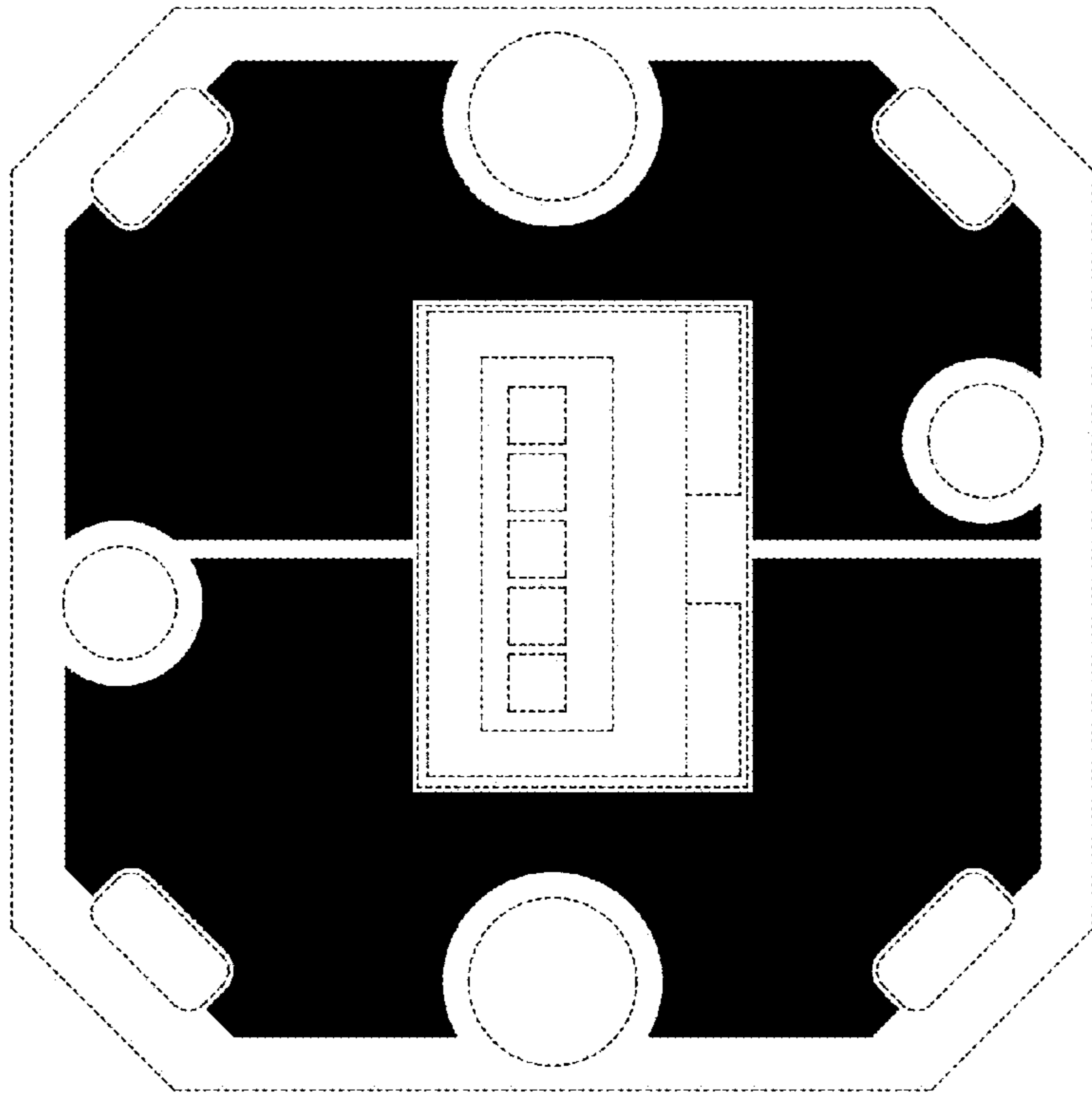


FIG. 2